

Layered Kagome Compound $\text{Na}_2\text{Ni}_3\text{S}_4$ with Topological Flat Band

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We report structural and electronic properties of $\text{Na}_2\text{Ni}_3\text{S}_4$, a quasi-two-dimensional compound composed of alternating layers of $[\text{Ni}_3\text{S}_4]^{2-}$ and Na^+ . The compound features a remarkable Ni-based kagome lattice with a square planar configuration of four surrounding S atoms for each Ni atom. Magnetization and electrical measurements reveal a weak paramagnetic insulator with a gap of about 0.5 eV. Our band structure calculation highlights a set of topological flat bands of the kagome lattice derived from the rotated d_{x^2} -orbital with $C_3 + T$ symmetry in the presence of crystal-field splitting.

I. INTRODUCTION

Kagome lattice has garnered significant attention in the community of condensed matter physics since the concept was introduced by Syozi [1]. A kagome lattice is a two-dimensional lattice pattern consisting of corner-sharing triangles, which is characterized by a large degree of geometrical frustration, and as a result, it can bear exotic quantum states such as quantum spin liquid [2, 3]. On the other hand, a kagome lattice typically generates the electronic structure characterized by a Dirac point (DP) at the Brillouin zone (BZ) corner, a saddle point at the BZ boundary, and a flat band (FB) over the whole BZ, which are the source for nontrivial band topology [4]. With the inclusion of magnetism and spin-orbit coupling (SOC), the electrons can realize a strongly interacting topological phase in a kagome lattice [5]. Recent studies have revealed various quantum physical properties in transition-metal-based kagome materials. For example, charge density wave (CDW) order and superconductivity were observed in a family of vanadium-based layered kagome materials AV_3Sb_5 ($A = \text{K}, \text{Rb}, \text{Cs}$) [6–8]. Spectrum measurements revealed the existence of the massive Dirac Fermion on the transition-metal-based kagome lattices in Fe_3Sn_2 [9] and TbMn_6Sn_6 [10] which generate significant berry curvature field and anomalous Hall effect.

The geometric frustration of a kagome lattice can cause destructive quantum interference, leading to a dispersionless FB in the momentum space. Such FB is prone to various instabilities aroused by electron-electron interactions, which can lead to various exotic many-body phenomena, such as superconductivity [11, 12], fractional quantum anomalous Hall [13], ferromagnetism [14–16], excitonic insulator [17] and Wigner crystals [18, 19]. The FBs can have flatness-protected touching points with dispersive band, leading to various topological phases [20],

including Chern insulators [21, 22], fractional quantum Hall insulators [23–26], topological insulators [27–29] and Weyl semimetals [30] when they are subjected to time-reversal symmetry (TRS) breaking and SOC.

Although correlated topological phases have been observed in Moire mini-FBs in twisted bilayer graphene and transition metal dichalcogenides [11, 31, 32], the FB still needs to be explored in bulk kagome materials. The dispersionless FB in kagome lattice requests a perfect phase cancellation, in which an isotropic nearest-neighbor single-particle hopping interaction is critical. Besides the simplest kagome lattice model assuming an s-orbital per lattice site, the physical underpinning for the existence of ideal FB in the transition-metals based kagome lattice is largely unknown. Most materials found in the laboratory involve multiple orbitals that defy such simplistic theoretical models. As a result, the observed FBs in many transition-metal-based kagome metals feature significant dispersion due to the character of the contributing orbitals and the accompanying anisotropic inter-orbital hopping [33–36].

To search for the potential FB in kagome compounds, we synthesize a new layered Ni-based kagome compound $\text{Na}_2\text{Ni}_3\text{S}_4$. This compound belongs to a group of compounds having the chemical formula of $\text{A}_2\text{T}_3\text{Ch}_4$, where A is the alkali metal including Li, Na, K, and Rb, T is a divalent transition metal such as Ni, Pd, Zn, and Mn, and Ch is S and Se [37–47]. These compounds obey the 18-electron rule and are highly insulative. They crystallize in various layered structures which are built up by stacking $[\text{T}_3\text{Ch}_4]^{2-}$ and A^+ layers alternatively [40]. Most of $\text{A}_2\text{T}_3\text{Ch}_4$ compounds crystallize in the $\text{Cs}_2\text{Zn}_3\text{S}_4$ -type structure in which the $[\text{T}_3\text{Ch}_4]^{2-}$ layer consists of edge-sharing TCh_4 tetrahedra [47]. On the other hand, when the transition metal is Ni and Pd, the compounds crystallize in orthorhombic structures in which the $[\text{Ni}_3\text{Ch}_4]^{2-}$ and $[\text{Pd}_3\text{Ch}_4]^{2-}$ layers consist of distorted double layers Ch-based honeycomb lattice and Ni(Pd)-based kagome lattice [46]. Each Ni(Pd) atom is located at the center of four Ch atoms in a rectangle planer configuration. The single crystals of these quasi-two-dimensional compounds

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can be easily mechanically cleaved.

The $A_2Ni(Pd)_3Ch_4$ compounds are all highly insulating with a band gap of about 1 eV [40, 42, 44–46, 48]. Because the divalent nickel and palladium cations manifest a low spin configuration $3d^8$ with S being 0, they in general demonstrate weak diamagnetic or paramagnetic signal [46]. However, it was reported that the $Rb_2Ni_3S_4$ specimens have a small residual ferromagnetic moment if they were soaked in water [48]. This unexpected ferromagnetism was attractive because it may be related to a long-sought flat-band ferromagnetism characteristic of a kagome lattice [49]. A recent study observed metal-insulator transition and superconductivity in $Rb_2Pd_3Se_4$ under high pressure [50]. The electronic structures of $A_2Ni(Pd)_3Ch_4$ compounds are highlighted by a manifold of narrow bands just below the Fermi level E_F which are derived from the hybridization between the Ni(Pd) d and Ch p states [43]. This manifold of bands has very narrow bandwidth and sharp density of states and therefore they were regarded as dispersionless FBs in the literature [51]. However the orbital characterization and energy dispersion of these bands remain largely unknown. The characteristic topological FBs of the kagome lattice have not been observed in the electronic states of $A_2Ni(Pd)_3Ch_4$.

In this research, we report the structural and electronic properties of a new compound $Na_2Ni_3S_4$ which built up by stacking $[Ni_3S_4]^{2-}$ and multiple Na^+ layers alternatively. Unlike the other $A_2Ni(Pd)_3Ch_4$ compounds, the Ni-based kagome lattice has no structural distortion and therefore a perfect phase cancellation is plausible. Physical property measurements reveal it as a weak paramagnetic insulator with a band gap about 0.5 eV. Moreover, the electronic band structure calculation shows there is a set of highly two-dimensional, three-band manifold derived from d_{xz} -orbital below the Fermi level. This manifold contains an FB with a touching point with the dispersive band along the $\Gamma - A$ direction, a van Hove singularity, and a Dirac crossing point, all characterized for a kagome lattice. The perfect FB is formed due to the rotation of d_{xz} -orbital on the kagome lattice caused by the crystal field splitting which conforms to the $C_3 + T$ symmetry [35]. Such coordination of Ni atoms satisfies the exacting destructive interference which is rarely observed in real materials.

II. METHODS

The process of synthesizing crystals of $Na_2Ni_3S_4$ involves a carbonate-flux method [46] in which Na_2CO_3 (99%), Ni (99.98%), and S (99.999%) were mixed in a molar ratio of 5 : 1 : 12 and loaded into an alumina crucible. The mixture was then heated in a tube furnace with flowing argon gas in which the temperature was gradually increased to 890 °C at a rate of 10 °C/min. After 180 minutes, the furnace was turned off and yellow chunks containing crystals with mm in size yielded. The chunks can be dissociated into water and the flake-shaped

crystals were obtained.

Single-crystal X-ray diffraction (XRD) measurement using Bruker D8 Eco-Quest Diffractometer with Mo radiation ($\lambda_{K\alpha} = 0.71073 \text{ \AA}$) was carried out at room temperature. Several crystals with the size about $50 \mu\text{m} \times 50 \mu\text{m} \times 20 \mu\text{m}$ were picked up and tested. Figure 1 (a), (b), and (c) depict precession images derived from the diffraction data in different directions. The frames were integrated with the Bruker SAINT software package using a narrow-frame algorithm. The integration of the data using a hexagonal unit cell in the space group of $P6/mmm$, which are based upon the refinement of the XYZ-centroids. Data were corrected for absorption effects using the Multi-Scan method (SADABS). The crystal structure of $Na_2Ni_3S_4$, as shown in Fig. 1(d), was refined using the direct method and full-matrix least-squares on the F^2 model with the SHELXTL software. The cell constants of $Na_2Ni_3S_4$ are $a = b = 5.656(5) \text{ \AA}$; $c = 8.930(12) \text{ \AA}$, $V = 247.4(6) \text{ \AA}^3$. Table I provides comprehensive details on the crystal structure of $Na_2Ni_3S_4$.

A Quantum Design magnetic property measurement system (MPMS-3) was used to perform the magnetization measurement for several samples with the applied field direction being along the c -axis at different temperatures. Electric transport measurements for the single crystals were carried out in Quantum Design physical property measurement system (PPMS-9). Standard four-point method was adopted and gold paste was used as the contacts.

Density-functional theory (DFT) calculations were performed for the experimentally determined hexagonal unit cell, as shown in Table I, using Vienna ab-initio Simulation Package (VASP v6.3.0)[52, 53]. The calculations are carried out within generalized gradient approximation (GGA) using PBE-type functional and recommended projector augmented-wave (PAW) pseudopotential[54]. Plane wave energy cutoff is chosen to be 270 eV and an $8 \times 8 \times 8$ Γ -centered \mathbf{k} -mesh is used. Orbital characters of Kohn-Sham orbitals are calculated under the PAW framework.

III. RESULTS AND ANALYSIS

To demonstrate the unique structure of $Na_2Ni_3S_4$, we have performed X-ray diffraction measurements on several flakes of single-crystalline $A_2T_3Ch_4$ whose largest nature surface was attached in the pucks in Rigaku Mini-flux 600 using a Cu- $K\alpha$ radiation source. As shown in Fig. 1(e), the positions of the diffraction peaks represent the stacking spaces in the quasi-two-dimensional $A_2T_3Ch_4$ compounds. The space d is about 8.93 \AA for $Na_2Ni_3S_4$, which aligns with the c value obtained in the single-crystal X-ray diffraction. On the other hand, the d values are 6.80 \AA , 6.54 \AA and 6.50 \AA for $Rb_2Ni_3S_4$, $K_2Pd_3Se_4$ and $K_2Ni_3S_4$, respectively. This result reveals that the spacing of the Ni_3S_4 layer is the largest in the $A_2T_3Ch_4$ compounds, indicating a distinct stacking way

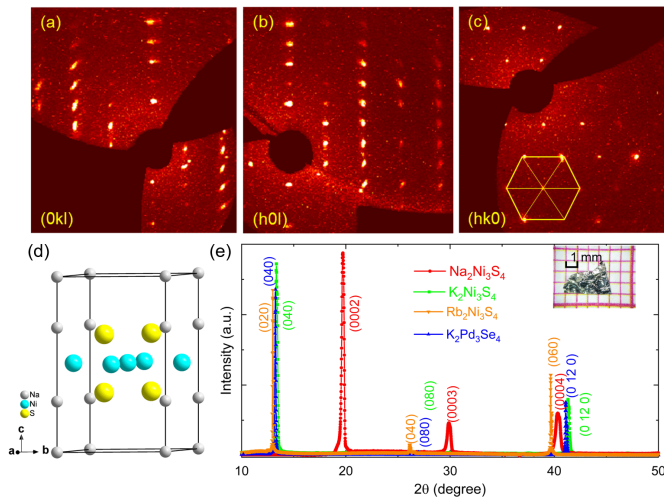


FIG. 1. Precession images calculated from single-crystal X-ray diffraction data (a) (0kl) plane, (b) (h0l) plane, and (c) (hk0) plane. The resolved spots are consistent with space group $P6/mmm$. (d) The schematic crystal structure of $\text{Na}_2\text{Ni}_3\text{S}_4$ (one unit cell). (e) The X-ray diffraction pattern of flakes of $\text{A}_2\text{T}_3\text{Ch}_4$ (The inset is a photo of $\text{Na}_2\text{Ni}_3\text{S}_4$ flake).

which will be discussed below.

Table 1. Single crystal structure refinement data for $\text{Na}_2\text{Ni}_3\text{S}_4$.

Empirical formula	$\text{Na}_2\text{Ni}_3\text{S}_4$
Formula weight (g/mol)	350.32
Temperature	300(2)
Crystal system	Hexagonal
Space group; Z	$P6/mmm$; 1
$a = b$ (Å)	5.656(5)
c (Å)	8.930(12)
Volume (Å ³)	247.4(6)
Extinction coefficient	0.7(4)
Theta range (°)	2.281 to 33.149
No. independent reflections	222
No. parameters	15
$R_1 : \omega R_2 (I > 2\delta(I))$	0.2309 : 0.4881
R indices (all data) $R_1 : \omega R_2$	0.2503 : 0.5147
Goodness-of-fit on F^2	1.992

Table 2. Atomic coordinates and equivalent isotropic displacement parameters of $\text{Na}_2\text{Ni}_3\text{S}_4$ system (U_{eq} is defined as one-third of the trace of the orthogonalized U_{ij} tensor (Å²)).

Atom	Wyck	x	y	z	Occ	U_{eq}
Ni	3g	1/2	0	1/2	1	0.021(3)
S	4h	1/3	1/3	0.3343(2)	1	0.028(3)
Na1	2e	0	0	0.290	0.667	0.032(9)
Na2	1a	0	0	0	0.667	0.028(9)

Figure 2(a) shows the temperature dependence of magnetic susceptibility for several pieces of $\text{Na}_2\text{Ni}_3\text{S}_4$ in a temperature range from 300 to 2 K when an external magnetic field $\mu_0 H = 1$ T was applied along the crystallographic c -axis. $\text{Na}_2\text{Ni}_3\text{S}_4$ exhibits temperature-independent paramagnetic signal at high temperature region and a Curie tail at low temperature region. We fit the susceptibility data below 30 K by using a constant

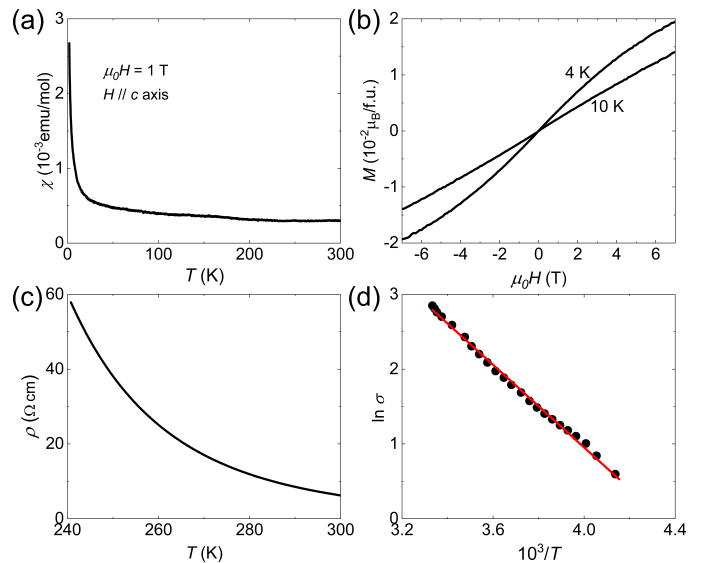


FIG. 2. (a) Temperature dependence of magnetic susceptibility of $\text{Na}_2\text{Ni}_3\text{S}_4$. An external magnetic field $\mu_0 H = 1$ T was applied along the crystallographic c -axis. (b) Field dependence of magnetization at 4 K and 10 K. (c) Temperature dependence resistivity of $\text{Na}_2\text{Ni}_3\text{S}_4$. (d) Fitting of the logarithm of conductance versus the reciprocal of temperature.

term χ_0 plus a Curie term $\frac{C}{T}$. The fitting data are $\chi_0 = 3.6 \times 10^{-4}$ emu/mol and $C = 0.004$ emu K/mol, leading to an effective moment being $0.14 \mu_B$ per formula unit, which likely comes from some magnetic impurity. Figure 2(b) shows the field dependence of magnetization up to 7 T at 4 K and 10 K. One can see a strict linear relation between M and H at 10 K while the M curve at 4 K seems to be the linear background plus a paramagnetic contribution which is saturated at about 4 T. These observations confirm that the magnetization of the sample consists of a small Curie term of the localized moments and a temperature-independent paramagnetic term, which are likely due to extrinsic sources, such as lattice imperfections and impurity. We notice the magnetization of $\text{Na}_2\text{Ni}_3\text{S}_4$ is distinct from the weak ferromagnetization of $\text{Rb}_2\text{Ni}_3\text{S}_4$ whose origin is not clear at this point [44].

Figure 2(c) shows a semiconductor-like, temperature dependence of the resistivity in $\text{Na}_2\text{Ni}_3\text{S}_4$ from 300 K to 240 K. The values of the resistivity are comparable to those for $\text{Rb}_2\text{Ni}_3\text{S}_4$ [44] and below 240 K they are beyond the capacity of our instrument. As shown in Fig. 2(d), an energy of activation E_g is estimated as 0.48 eV by using the formula of $\sigma = Ae^{(-E_g/2k_B T)}$, which is close to the value of $\text{Rb}_2\text{Ni}_3\text{S}_4$ at high temperatures [44].

In order to better understand the electronic structure of $\text{Na}_2\text{Ni}_3\text{S}_4$, we utilized a DFT calculation in generalized gradient approximation. To simplify the calculation, we assume that Na atoms are located at the $2e$ position, which preserves the average structural symmetry

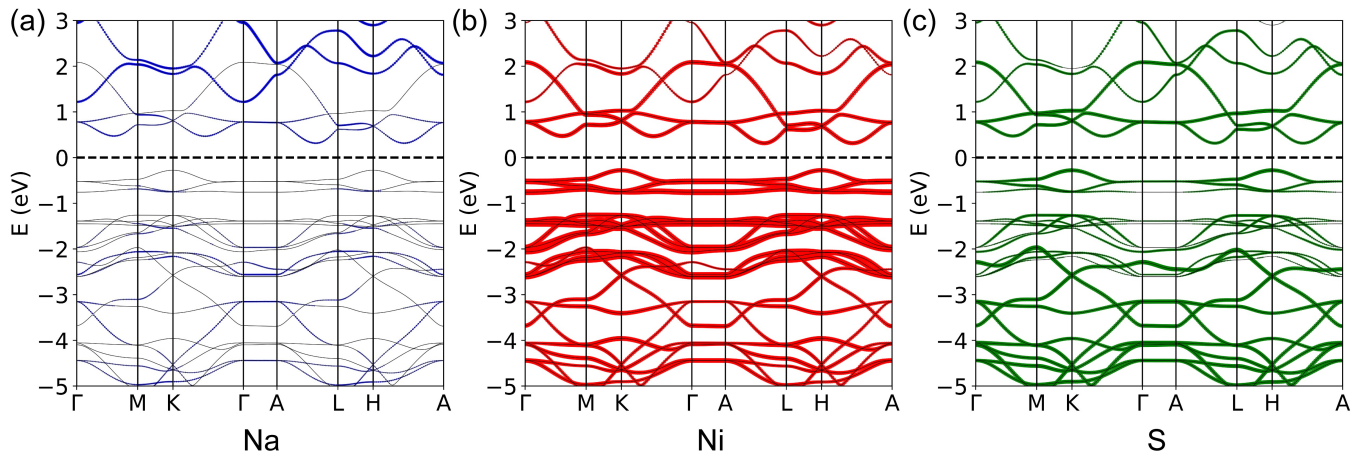


FIG. 3. Atomic projected band structure of $\text{Na}_2\text{Ni}_3\text{S}_4$ for atoms (a) Na, (b) Ni, and (c) S.

$P6/mmm$. Figure 3 (a), (b) and (c) are the atomic projected band structure with respect to Na, Ni and S respectively. Na hardly contributes to the energy band within the range from 0 to -5 eV. On the other hand, Ni and S have strong hybridization in the calculated energy range. The electronic structure has an indirect band gap of 0.75 eV with no state around E_F , which is slightly larger than the estimation on the temperature dependent resistivity. Below E_F there is a narrow three-band manifold which is isolated with the deeper bands with a gap about 0.6 eV. This three-band manifold is somehow similar as what observed in the band structures of $\text{Rb}_2\text{Ni}_3\text{S}_4$ [43] and $\text{Rb}_2\text{Pd}_3\text{Se}_4$ [50] but the bandwidth for $\text{Na}_2\text{Ni}_3\text{S}_4$ (0.5 eV) is more narrow.

Because the Ni atoms are located in a square planar coordination of sulfur with the site symmetry of D_{2h} , the five-fold degenerate d -orbitals of Ni will split into 5 manifolds under the orthorhombic crystal electric field. We take into account the local xyz coordination for the square plane of Ni atom and analyze the atomic d orbitals as shown in Fig. 4. The three-band manifold has d_{xy} and d_{z^2} character. To clarify whether there exist topological FB in the three-band manifold, we zoomed in the electronic energy dispersion in the range of 0 to -1 eV in Fig. 5. The apparently FB at -0.75 eV indeed comes from two bands which cross at K and H points. The touching point in K is a linear-dispersed Dirac point ubiquitous in the kagome lattice. This is clear that the characteristic topological FB of kagome lattice is absent in this three-band manifold just below E_F .

On the other hand, there is another highly two-dimensional, three-band manifold derived from d_{xz} -orbital between -3 and -5 eV without other d -orbital. This manifold contains an FB at about -3.2 eV with the bandwidth less than 0.2 eV, a van Hove singularity at -4.0 eV, and a Dirac crossing point at the K and H points at -4.5 eV. The FB touches with the dispersive band along the $\Gamma - A$ direction. All these features are characterized

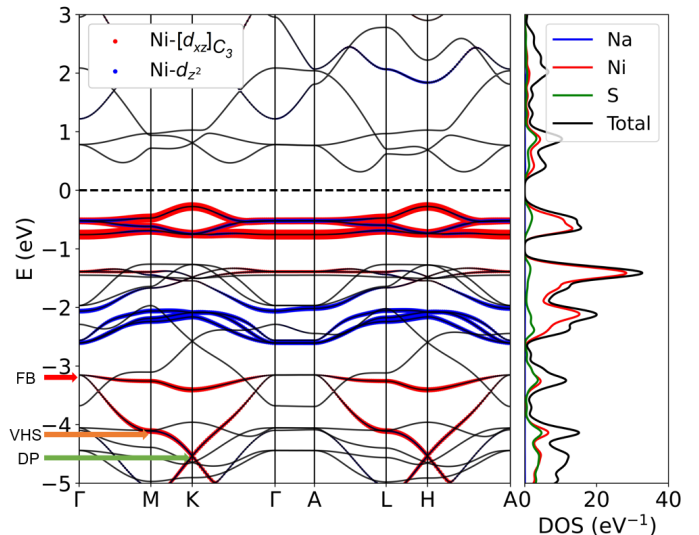


FIG. 4. Band structure (left) and atomic projected density of state (right) of $\text{Na}_2\text{Ni}_3\text{S}_4$ calculated by DFT. Band resolved projected density of state of $C_3 + T$ symmetry-adapted d_{xz} orbitals is highlighted in band structure as red, and d_{z^2} orbital as blue.

for a kagome lattice[20] which is absent in the electronic structure for the other $\text{A}_2\text{T}_3\text{Ch}_4$ compounds.

IV. DISCUSSION

We now comparably demonstrate the crystal structures of $\text{Na}_2\text{Ni}_3\text{S}_4$ and $\text{K}_2\text{Ni}_3\text{S}_4$ as representative for the other $\text{A}_2\text{Ni}(\text{Pd})_3\text{Ch}_4$ compounds in Fig. 6. The most significant difference is that the Na atoms occupy 2/3 of the two different crystallographic sites equivalently in $\text{Na}_2\text{Ni}_3\text{S}_4$ whereas the alkali atoms fully occupy only one

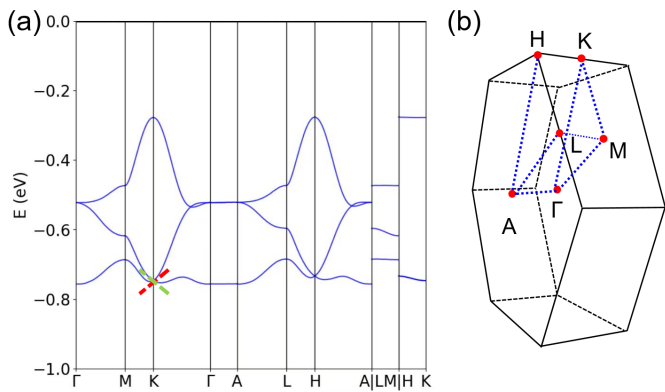


FIG. 5. Calculated electronic energy dispersion of $\text{Na}_2\text{Ni}_3\text{S}_4$ in the range of 0 to -1.0 eV.

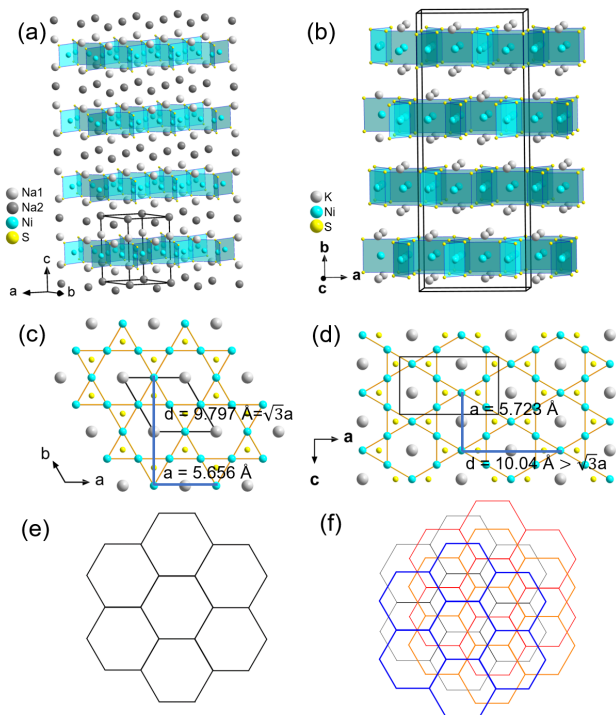


FIG. 6. (a), (b) Schematic diagram of the crystal structure of the $\text{Na}_2\text{Ni}_3\text{S}_4$ and $\text{K}_2\text{Ni}_3\text{S}_4$. (c) A Ni-based kagome layer in $\text{Na}_2\text{Ni}_3\text{S}_4$ ($P6/mmm$), and (d) A distorted Ni-based kagome layer in $\text{K}_2\text{Ni}_3\text{S}_4$ ($Fddd$). (e) The stacking of the S-based honeycomb lattices in $\text{Na}_2\text{Ni}_3\text{S}_4$. (f) The stacking of the S-based honeycomb lattices in $\text{K}_2\text{Ni}_3\text{S}_4$.

crystallographic site in the other $\text{A}_2\text{Ni}(\text{Pd})_3\text{Ch}_4$ compounds. In $\text{Na}_2\text{Ni}_3\text{S}_4$, the Na1 site is located upper and down the center of the six sulfur rings from the Ni_3S_4 slab while the Na2 site is sandwiched between the two Na1 site along the c axis. The existence of this additional Na^+ layer makes a significant large spacing (8.93Å), 40% larger than that in other $\text{A}_2\text{T}_3\text{Ch}_4$ compounds with no

such site. On the other hand, the staggered stacking of the Ni_3S_4 -K-K- Ni_3S_4 layers leads to a quadruple b axis in $\text{K}_2\text{Ni}_3\text{S}_4$ [40], making the sulfur honeycomb in the Ni_3S_4 layer repeat itself in every four layers, as shown in Fig. 6 (f).

The structure of the Ni_3S_4 layer also has pronounced difference between $\text{Na}_2\text{Ni}_3\text{S}_4$ and the other $\text{A}_2\text{Ni}(\text{Pd})_3\text{Ch}_4$ compounds. In $\text{Na}_2\text{Ni}_3\text{S}_4$, the Ni_3S_4 layer is formed by the linked edge-sharing NiS_4 square plane in such a way as to define two honeycomb network of S and one kagome network of Ni in between. This NiS_4 square plane reads the Ni-S distance being about 2.205Å and the S-Ni-S angles being 84.478° and 95.522°, close to a perfect sulfur square planar coordination. The Ni-based kagome lattice has no distortion and the Ni-Ni distance is 2.828(3)Å equivalently, which is about 6% higher than the Ni-Ni contacts in nickel metal [40], indicating strong atomic interactions between the Ni atoms.

In the other $\text{A}_2\text{Ni}(\text{Pd})_3\text{Ch}_4$ compounds, the Ni_3S_4 layer is stretched along the c direction, leading to two crystallographic sites for the Ni atoms. As the result, the Ni-S bondlengths have about 0.4% difference for the two Ni sites in the NiS_4 square plane. The S-Ni-S bond angles for the two Ni sites range from 82.572° to 97.447° and 82.908° to 98.399°, respectively [40]. The distorted Ni-based kagome is characterized by different Ni-Ni distance, ranging from 2.862 Å to 2.889 Å.

The perfect Ni-based kagome lattice seems to exist in $\text{Na}_2\text{Ni}_3\text{S}_4$ uniquely for all $\text{A}_2\text{T}_3\text{Ch}_4$ compounds. As pointed out by Ref. [37], large alkali metal ions can cause lattice distortion in these layer structural compounds. Nevertheless, the existence of the additional Na^+ layer plays a crucial role for forming the perfect kagome lattice which is critical for the existence of a topological FB.

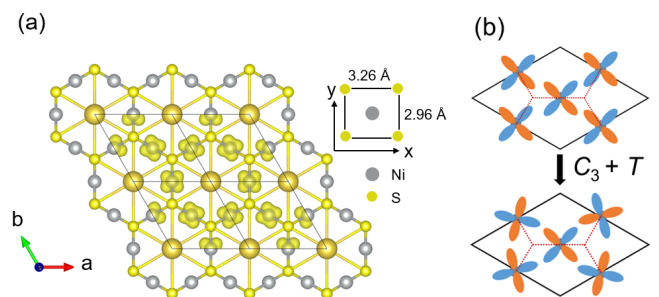


FIG. 7. (a) The charge density of the FBs immediately below the Fermi level manifests the character of $C_3 + T$ symmetry-adapted d_{xz} orbitals. The upper right inset is a schematic diagram of the rectangular coordination environment of Ni-S in $\text{Na}_2\text{Ni}_3\text{S}_4$. (b) Illustration of d_{xz} orbital with $C_3 + T$ rotation to produce a FB. The black and red curves represent bands without and with rotation, respectively.

In a kagome lattice, the perfect destructive interference often relies on a tight-binding model of s -orbitals, requiring a single rotational invariant orbital on each site with isotropic hopping [35]. Obviously a distorted kagome

lattice with two sets of Ni-Ni distances, such as those in the other $A_2T_3Ch_4$ compounds, cannot own isotropic hopping and perfect destructive interference. For the d_{xy} , $d_{x^2-y^2}$, d_{xz} , and d_{yz} orbitals, Kim *et al.* pointed out that the properly rotated d -orbital can form perfect FBs on kagome lattice if they conform to the underlying kagome lattice symmetry, most notably C_3 rotation plus translation ($C_3 + T$) [35]. The resultant FB will have the same shape as that of the s -orbital model, possessing a quadratic touching point with another dispersive band.

The above theoretical analysis help us to understand why the topological FB of d_{xz} orbitals remain intact in $Na_2Ni_3S_4$. The crystal electric field of the square planar coordination of sulfur orients in such direction of the kagome lattice that the properly rotated d_{xz} orbital preserve the three-fold rotation symmetry $C_3 + T$ of the crystals. As shown in Fig. 7(a), the partial charge at each site has the shape of d_{xz} and manifests the d_{xz} orbital character on each Ni atom in its orthorhombic local coordinate. Therefore the highly two-dimensional, three-band manifold purely derived from d_{xz} -orbital between -3 and -5 eV generate a set of ideal topological FB of kagome lattice. On the other hand, the d_{z^2} orbitals need a weak π bonding to hopping inter-site. The hybridization between the d_{xz} and d_{z^2} orbitals interrupts perfect destructive interference and therefore the topological FB is absent in the three manifold just below E_F .

V. CONCLUSION

In summary, we have synthesized a new layered kagome compound $Na_2Ni_3S_4$ which demonstrates novel crystal

structure, highlighted by a large layer-layer spacing and perfect Ni-based kagome lattice. The calculated band structure shows that there is a set of three-band manifold derived from d_{xz} -orbital between -3 and -5 eV which contains FB, Dirac point and saddle point, all characterized by the kagome lattice. Because the formation of FBs in $Na_2Ni_3S_4$ is due to the rotation of d_{xz} -orbital which conforms to the $C_3 + T$ symmetry, such construction promises a perfect destructive interference which is rarely observed in real materials.

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